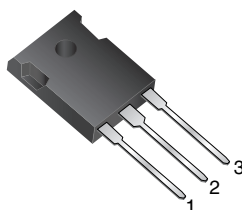


Dual Common-Cathode Schottky Rectifier



TO-247AD (TO-3P)



PRIMARY CHARACTERISTICS

$I_{F(AV)}$	2 x 30 A
V_{RRM}	35 V, 45 V, 60 V
I_{FSM}	350 A
V_F at $I_F = 30$ A	0.50 V, 0.56 V
T_J max.	150 °C

FEATURES

- Guardring for overvoltage protection
- Low power losses, high efficiency
- Low forward voltage drop
- High forward surge capability
- High frequency operation
- Solder dip 260 °C, 40 s
- Component in accordance to RoHS 2002/95/EC and WEEE 2002/96/EC



RoHS
COMPLIANT

TYPICAL APPLICATIONS

For use in low voltage, high frequency rectifier of switching mode power supplies, freewheeling diodes, dc-to-dc converters or polarity protection application.

MECHANICAL DATA

Case: TO-247AD (TO-3P)

Epoxy meets UL 94V-0 flammability rating

Terminals: Matte tin plated leads, solderable per J-STD-002 and JESD22-B102

E3 suffix for consumer grade, meets JESD 201 class 1A whisker test

Polarity: As marked

Mounting Torque: 10 in-lbs maximum

MAXIMUM RATINGS ($T_A = 25$ °C unless otherwise noted)

PARAMETER	SYMBOL	M6035P	M6045P	M6060P	UNIT
Maximum repetitive peak reverse voltage	V_{RRM}	35	45	60	V
Maximum average forward rectified total device current (Fig. 1) per diode	$I_{F(AV)}$	60 30			A
Peak forward surge current 8.3 ms single half sine-wave superimposed on rated load per diode	I_{FSM}	350			A
Peak repetitive reverse current at $t_p = 2$ μ s, 1 kHz per diode	I_{RRM}	2.0			A
Voltage rate of change (rated V_R)	dV/dt	10 000			V/ μ s
Operating junction and storage temperature range	T_J, T_{STG}	- 65 to + 150			°C

ELECTRICAL CHARACTERISTICS (T _A = 25 °C unless otherwise noted)								
PARAMETER	TEST CONDITIONS		SYMBOL	M6035P	M6045P	M6060P		UNIT
				TYP.	MAX.	TYP.	MAX.	
Instantaneous forward voltage per diode ⁽¹⁾	I _F = 10 A	T _J = 25 °C	V _F	0.42	-	0.43	-	V
	I _F = 20 A			0.49	-	0.52	-	
	I _F = 30 A			0.54	0.60	0.59	0.64	
	I _F = 10 A	T _J = 125 °C		0.31	-	0.33	-	
	I _F = 20 A			0.42	-	0.47	-	
	I _F = 30 A			0.50	0.55	0.56	0.60	
Reverse current per diode ⁽²⁾	V _R	T _J = 25 °C T _J = 125 °C	I _R	135	600	240	600	μA
				110	160	140	160	mA
Typical junction capacitance	4.0 V, 1 MHz		C _J	1150	-	1090	-	pF

Notes:(1) Pulse test: 300 μs pulse width, 1 % duty cycle(2) Pulse test: Pulse width $\leq 40\text{ ms}$

THERMAL CHARACTERISTICS ($T_A = 25\text{ }^{\circ}\text{C}$ unless otherwise noted)					
PARAMETER	SYMBOL	M6035P	M6045P	M6060P	UNIT
Typical thermal resistance per diode	$R_{\theta JC}$	2.0			$^{\circ}\text{C/W}$

ORDERING INFORMATION (Example)				
PREFERRED P/N	UNIT WEIGHT (g)	PREFERRED PACKAGE CODE	BASE QUANTITY	DELIVERY MODE
M6045P-E3/45	6.14	45	30/tube	Tube
M6060P-E3/45	6.14	45	30/tube	Tube

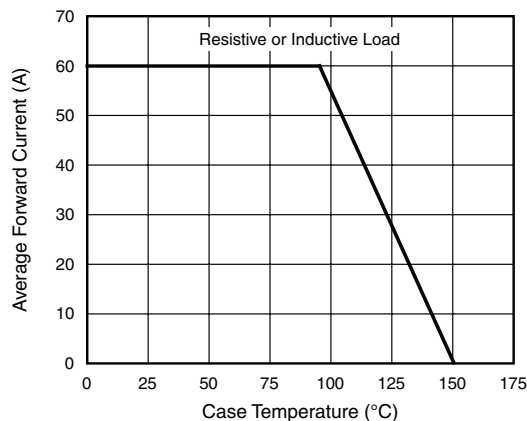
RATINGS AND CHARACTERISTICS CURVES($T_A = 25\text{ }^{\circ}\text{C}$ unless otherwise noted)

Figure 1. Forward Current Derating Curve

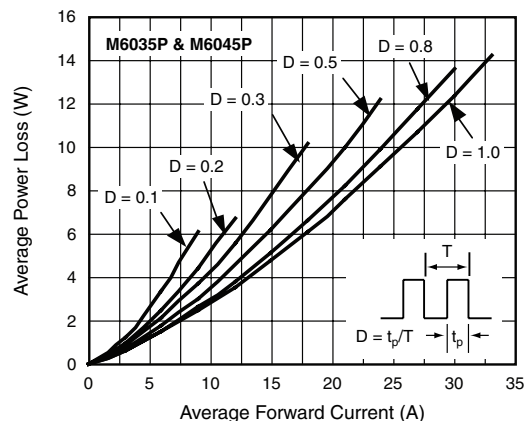


Figure 2. Forward Power Loss Characteristics Per Diode

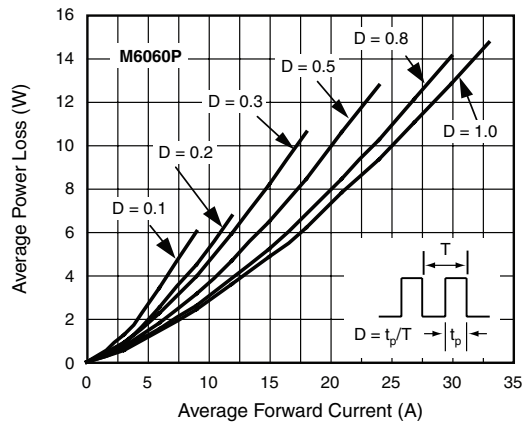


Figure 3. Forward Power Loss Characteristics Per Diode

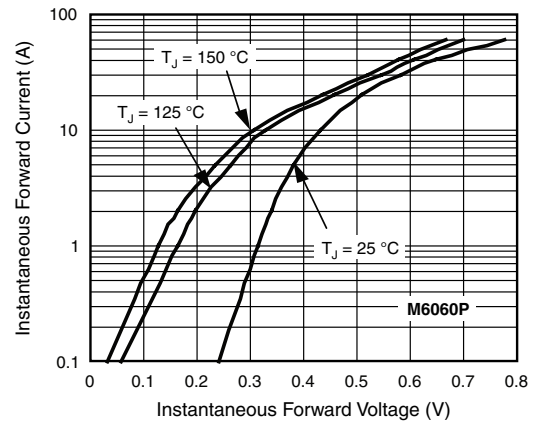


Figure 6. Typical Instantaneous Forward Characteristics Per Diode

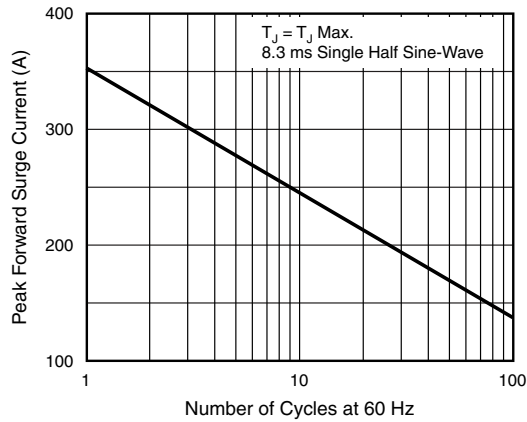


Figure 4. Maximum Non-Repetitive Peak Forward Surge Current Per Diode

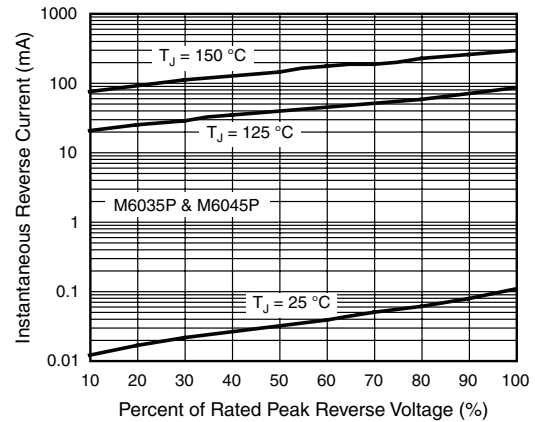


Figure 7. Typical Reverse Characteristics Per Diode

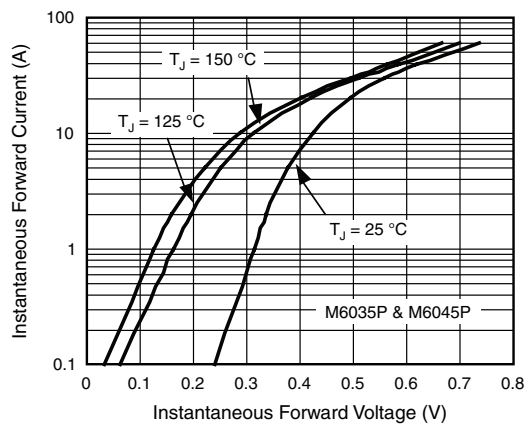


Figure 5. Typical Instantaneous Forward Characteristics Per Diode

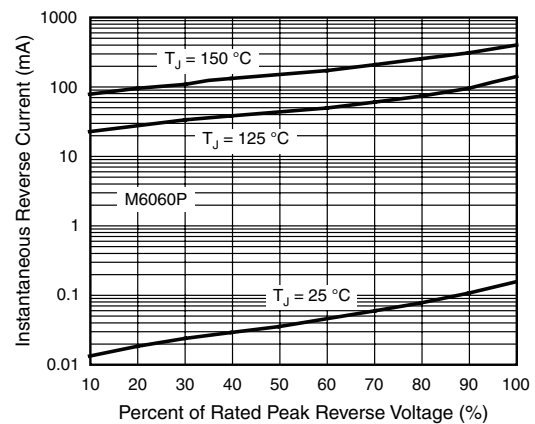


Figure 8. Typical Reverse Characteristics Per Diode

M6035P thru M6060P

Vishay General Semiconductor

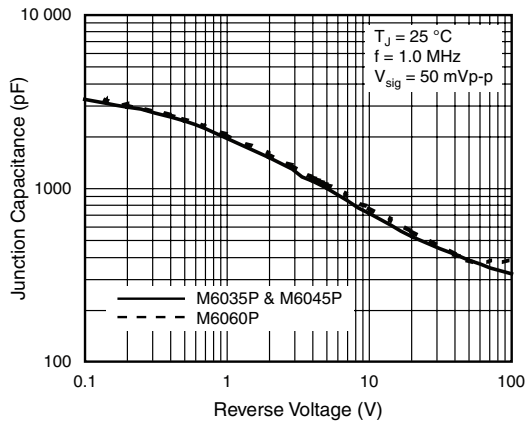


Figure 9. Typical Junction Capacitance Per Diode

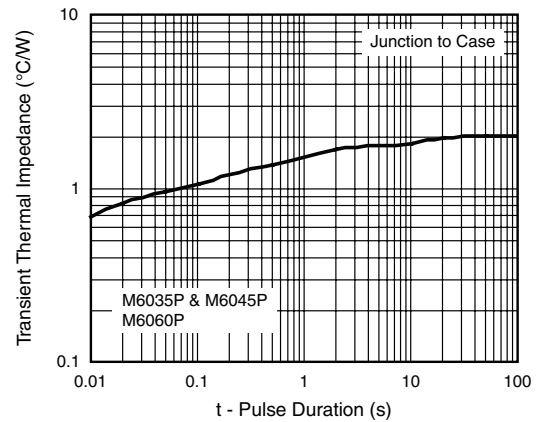
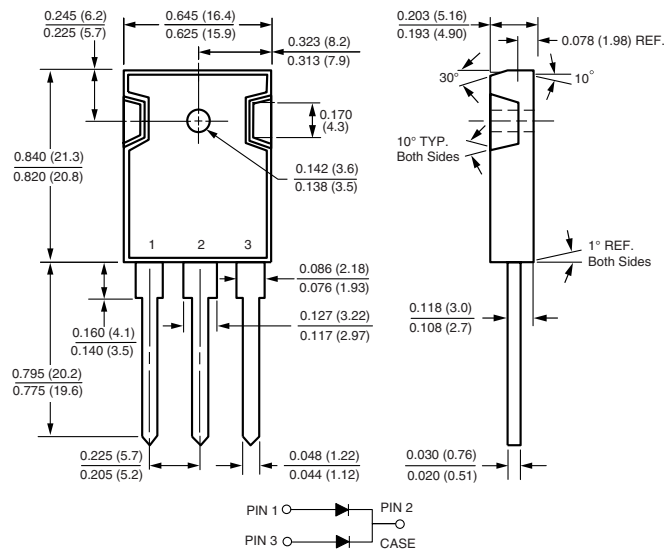


Figure 10. Typical Transient Thermal Impedance Per Diode

PACKAGE OUTLINE DIMENSIONS in inches (millimeters)**TO-247AD (TO-3P)**



Disclaimer

All product specifications and data are subject to change without notice.

Vishay Intertechnology, Inc., its affiliates, agents, and employees, and all persons acting on its or their behalf (collectively, "Vishay"), disclaim any and all liability for any errors, inaccuracies or incompleteness contained herein or in any other disclosure relating to any product.

Vishay disclaims any and all liability arising out of the use or application of any product described herein or of any information provided herein to the maximum extent permitted by law. The product specifications do not expand or otherwise modify Vishay's terms and conditions of purchase, including but not limited to the warranty expressed therein, which apply to these products.

No license, express or implied, by estoppel or otherwise, to any intellectual property rights is granted by this document or by any conduct of Vishay.

The products shown herein are not designed for use in medical, life-saving, or life-sustaining applications unless otherwise expressly indicated. Customers using or selling Vishay products not expressly indicated for use in such applications do so entirely at their own risk and agree to fully indemnify Vishay for any damages arising or resulting from such use or sale. Please contact authorized Vishay personnel to obtain written terms and conditions regarding products designed for such applications.

Product names and markings noted herein may be trademarks of their respective owners.